



2DB1386Q/R

20V PNP MEDIUM POWER TRANSISTOR IN SOT89

Features

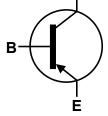
- BV_{CEO} > -20V
- I_C = -5A high Continuous Current
- Low saturation voltage V_{CE(sat)} < -1V @ -4A
- Complementary NPN Type: 2DD2098
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

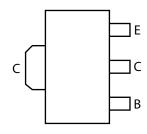
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.052 grams (approximate)









Top View

Device Symbol

Pin Out – Top View

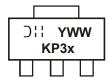
Ordering Information (Note 4)

| ſ | Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---|--------------|---------|--------------------|-----------------|-------------------|
| | 2DB1386Q-13 | KP3Q | 13 | 12 | 2,500 |
| | 2DB1386Q-13R | KP3Q | 13 | 12 | 4,000 |
| | 2DB1386R-13 | KP3R | 13 | 12 | 2,500 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



KP3x = Product Type Marking Code, where: KP3Q = 2DB1386Q

KP3R = 2DB1386R

YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -30 | V |
| Collector-Emitter Voltage | V_{CEO} | -20 | V |
| Emitter-Base Voltage | V_{EBO} | -6 | V |
| Continuous Collector Current | Ic | -5 | Α |
| Peak Pulse Current | I _{CM} | -10 | Α |
| Base Current | Ι _Β | -500 | mA |

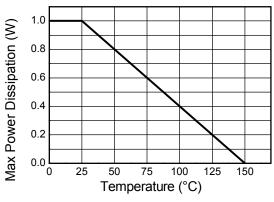
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

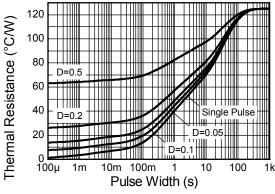
| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 1 | W |
| Thermal Resistance, Junction to Ambient Air (Note 5) | $R_{	hetaJA}$ | 125 | °C/W |
| Thermal Resistance, Junction to Leads (Note 6) | $R_{	heta JL}$ | 19 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Notes:

- 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

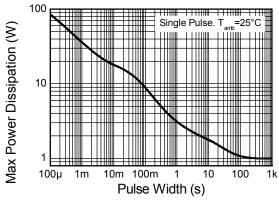
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation

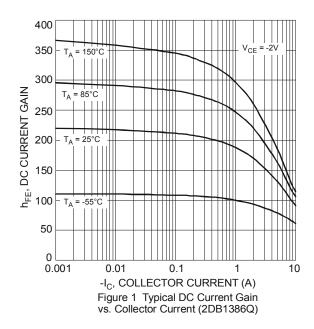


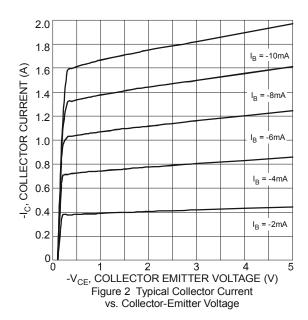
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Min | Тур | Max | Unit | Conditions |
|--------------------------------------|------------------------------|----------------------|-----|-------|------|------|---|
| OFF CHARACTERISTICS (N | OFF CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Base Breakdown Voltage | | BV _{CBO} | -30 | _ | _ | V | $I_C = -50\mu A$, $I_E = 0$ |
| Collector-Emitter Breakdown Voltage | | BV _{CEO} | -20 | | | V | $I_{C} = -1 \text{mA}, I_{B} = 0$ |
| Emitter-Base Breakdown Voltage | | BV _{EBO} | -6 | _ | | V | $I_E = -50\mu A, I_C = 0$ |
| Collector Cut-Off Current | | I _{CBO} | _ | _ | -0.5 | μΑ | $V_{CB} = -20V, I_{E} = 0$ |
| Emitter Cut-Off Current | | I _{EBO} | _ | _ | -0.5 | μΑ | $V_{EB} = -5V, I_{C} = 0$ |
| ON CHARACTERISTICS (No | ON CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Emitter Saturation Voltage | | V _{CE(SAT)} | _ | -0.25 | -1.0 | V | $I_C = -4A$, $I_B = -0.1A$ |
| DC Current Gain | 2DB1386Q | | 120 | _ | 270 | | $I_C = -0.5A$, $V_{CF} = -2V$ |
| DC Current Gain | 2DB1386R | | 180 | _ | 390 | _ | IC = -0.5A, VCE = -2V |
| SMALL SIGNAL CHARACTERISTICS | | | | | | | |
| Output Capacitance | | C_{obo} | _ | 55 | _ | pF | $V_{CB} = -20V$, $I_E = 0$, $f = 1MHz$ |
| Current Gain-Bandwidth Product | | f⊤ | _ | 100 | _ | MHz | V_{CE} = -6V, I_E = 50mA, f = 30MHz |

Notes: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







Typical Electrical Characteristics (cont.)

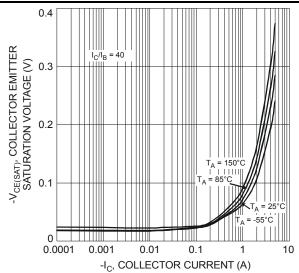


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

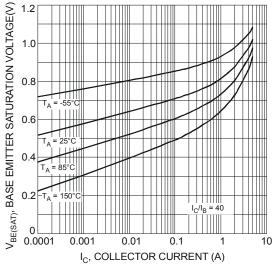


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

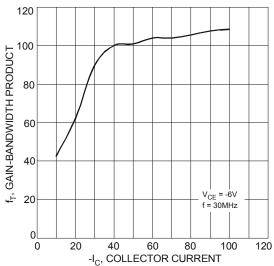


Figure 7 Typical Gain-Bandwidth Product vs. Collector Current

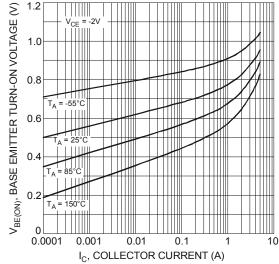


Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

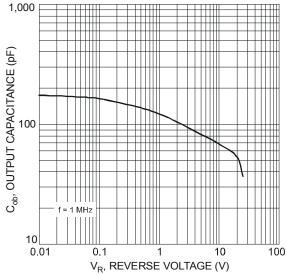
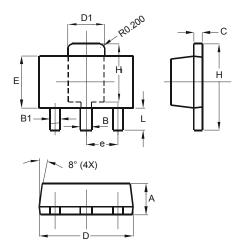


Figure 6 Typical Output Capacitance Characteristics



Package Outline Dimensions

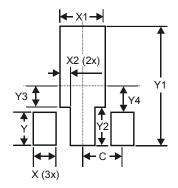
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT89 | | | | |
|----------------------|----------|------|--|--|
| Dim | Min | Max | | |
| Α | 1.40 | 1.60 | | |
| В | 0.44 | 0.62 | | |
| B1 | 0.35 | 0.54 | | |
| С | C 0.35 | | | |
| D | 4.40 | 4.60 | | |
| D1 | 1.62 | 1.83 | | |
| Е | 2.29 | 2.60 | | |
| е | 1.50 Typ | | | |
| Н | 3.94 | 4.25 | | |
| H1 | 2.63 | 2.93 | | |
| L | 0.89 | 1.20 | | |
| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Х | 0.900 |
| X1 | 1.733 |
| X2 | 0.416 |
| Υ | 1.300 |
| Y1 | 4.600 |
| Y2 | 1.475 |
| Y3 | 0.950 |
| Y4 | 1.125 |
| С | 1 500 |



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